

View Online at <https://aerobasegroup.com/nsn/5961-00-421-2993>

Inclosure Material:

Metal all transistor

Overall Length:

0.170 inches all transistor and 0.210 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.209 inches all transistor and 0.230 inches all transistor

Internal Configuration:

Field effect all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Terminal Circle Diameter:

0.100 inches all transistor

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon all transistor

Power Rating Per Characteristic:

300.0 milliwatts total device dissipation all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction all transistor

Special Features:

Each transistor is unitized

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Terminal Type And Quantity:

6 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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